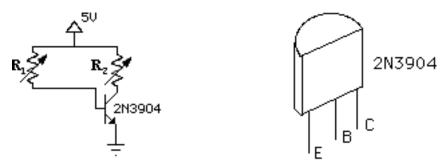
# Physics 4700 Experiment 4

#### Transistors - 1

1) Build the following circuit, with  $R_1 = 5$  M $\Omega$  and  $R_2 = 10$  k $\Omega$ . Vary  $I_B$  between 1 and 30  $\mu$ A. Measure  $V_{CE}$ , and  $I_C$ . Plot  $I_{C_1}$   $\beta$  (=  $h_{fe} = I_C/I_B$ ),  $V_{CE}$ , vs.  $I_B$ . Compare your results with the 2N3904 spec sheet.



- 2) Design a single stage common emitter amplifier. The amplifier should have the following specs:
- a) flat frequency response from 30 to 10 kHz (i.e. -3 dB point at 30 Hz)
- b) voltage gain of  $\approx 100$
- c) input impedance  $> 300 \Omega$
- 3) Measure the following properties of your amplifier and compare your results with expectations:
- a) DC voltages at operating point.
- b) plot voltage gain as a function of frequency (30-100 kHz).
- c) input and output impedance.
- d) capture a picture of the amp's output response to a large input sine wave.

# Suggested References:

Class notes of course.

Simpson Experiment 13 (P. 862) and 14 (P. 864).

Student Manual for Art of Electronics (most of Chapter 2).

# Designing the Common Emitter Amp

In this note I will outline a plan for designing a common emitter (CE) amplifier. There are many other ways of designing such an amp however they involve techniques beyond this class. Here are some good references on the subject:

Simpson: Section 5.7 (P. 221) and Experiment 14 (P. 865)

Diefenderfer: P. 152-154 Hayes and Horowitz: P. 115

A general purpose design for the CE amp is given in Fig. 1.  $R_1$  and  $R_2$  are bias resistors and are used to keep the transistor "turned on" for DC voltages  $(V_{cc})$ .  $R_C$  and  $R_E$  determine the gain of the amp and  $R_E$  plays a role in determining the input impedance of the amp.  $C_E$  provides a path to ground for AC signals, while  $C_{in}$  and  $C_{out}$  isolate the input and output of the amp from the DC voltages that are present on the transistor.

Some general rules to keep in mind:

- a) Our transistor amp amplifies <u>small</u> signals, typically mV.
- b) Typical DC collector current is a few mA.
- c) The gain  $(V_{\text{out}}/V_{\text{in}})$  of a CE amp is  $\approx R_{\text{C}}/r_{\text{BE}}$  if  $R_{\text{E}}=0$ .  $r_{\text{BE}}$  is intrinsic to the transistor. You can't touch it! It is given by:

$$r_{\rm BE} = h_{\rm ie}/h_{\rm fe} \approx 25 \text{ mV/}I_{\rm C}$$
. So if  $I_{\rm C} = 1 \text{ mA}$  then  $r_{\rm BE} = 25 \Omega$ .

(See Simpson P. 227, 244 or class notes or Hayes and Horowitz P. 113)

d) The AC input impedance of the transistor is  $\approx \beta r_{\rm BE}$  (or  $h_{\rm fe}r_{\rm be}$ ).

A typical  $\beta$  is 100. Remember that  $\beta = h_{\rm fe} = I_{\rm C}/I_{\rm B}$  so for 1 mA of collector current the AC input impedance is  $\approx (100)(25) = 2500 \ \Omega$ .

- e) The DC input impedance of the transistor is  $\approx \beta R_{\rm E}$  (or  $h_{\rm fe}R_{\rm E}$ ). A typical value of  $R_{\rm E}$  is 1 k $\Omega$ . So the DC impedance is much larger (e.g. 100 k vs. 2.5 k) than the AC impedance.
- f) Since  $I_E = I_C + I_B$  and  $I_B = I_C/\beta$  we assume that  $I_C = I_E$  for design purposes.
- g) In order to stabilize the transistor from problems due to heating we should have:

$$R_1 \parallel R_2 < 10 R_{\mathrm{E}}.$$

See Simpson (P. 215-221) or Diefenderfer (P. 148) for a discussion of thermal stability.

With rules a-g in mind we are ready to design the CE amplifier.

- 1) Pick  $V_{cc}$ . Let's use  $V_{cc} = 15$  Volts since all our lab supplies go up to this value.
- 2) We want the voltage gain  $G = V_{out}/V_{in} > 100$ . From rule c

$$G \approx R_{\rm C}/r_{\rm E} = R_{\rm C}/(25 \ \Omega/I_{\rm C}).$$

From the 2N3904 spec sheet (Fig. 2)  $I_{\rm C} = 2.5$  mA looks like good place to operate the transistor (any choice in the linear region of the transistor would be OK):

$$G \approx R_{\rm C}/10 > 100$$

$$R_{\rm C} > 1000 \ \Omega$$

Pick 
$$R_{\rm C} = 2000 \ \Omega$$
.

3) We now need to decide what the maximum collect current ( $I_{\rm C}$ ) we will allow. From the spec sheet 4 mA looks reasonable. Applying Kirchhoff's law to the circuit in Fig. 1 yields the following load line ( $I_{\rm C}$  vs.  $V_{\rm CE}$ ) equation:

$$I_{\rm C} = V_{\rm cc}/(R_{\rm E}+R_{\rm C}) - V_{\rm CE}/(R_{\rm E}+R_{\rm C})$$
 (when  $I_{\rm C}$  = 4 mA,  $V_{\rm CE}$  = 0 Volts and when  $I_{\rm C}$  = 0 mA,  $V_{\rm CE}$  = 15 Volts)

 $V_{\rm CE} \approx 5$ -6 Volts is in the linear region. From the spec sheet we see that  $I_{\rm B}$  must be  $\approx 10~\mu{\rm A}$ .

4) Using #3 from above we can find  $R_{\rm E}$ .

$$I_{\rm C}({\rm max}) = V_{\rm cc}/(R_{\rm E}+R_{\rm C}) = 4~{\rm mA} = 15~{\rm V}/(2000~\Omega+R_{\rm E})$$
  $R_{\rm E}=1.75~{\rm k}\Omega$ 

5) We can now find  $V_{\rm E}$  and thus  $V_{\rm B}$ .

$$V_{\rm E} = I_{\rm E} R_{\rm E} \approx I_{\rm C} R_{\rm E} = (2.5 \text{ mA})(1.75 \text{ k}\Omega)$$
  
 $V_{\rm E} \approx 4.4 \text{ Volts}$ 

Remember  $V_{\rm B} = V_{\rm E} + 0.6$  Volts for an NPN transistor.

$$V_{\rm B} \approx 5 \text{ Volts}$$

6) We can now find  $R_1$  and  $R_2$  since:

$$V_{\rm B} = [15 \text{ V}][R_2/(R_1 + R_2)] \text{ with } V_{\rm B} = 5 \text{ V}.$$

From rule g on P. 1 we need  $R_1 \parallel R_2 < 10 R_E = 17.5 \text{ k}\Omega$ .

Also  $R_1$  and  $R_2$  must provide enough base current  $(I_B \approx 10 \ \mu\text{A})$ 

$$V_{\rm cc}/(R_1 + R_2) >> I_{\rm B} \approx 10~\mu{\rm A}.$$

A choice of  $R_1$  and  $R_2$  that satisfies all of the above is:

$$R_1 = 10 \text{ k}\Omega$$
 and  $R_2 = 5 \text{ k}\Omega$ . There are many other choices.

7) The AC input impedance of the amp can now be calculated:

$$\begin{split} 1/Z_{\text{input}} \approx 1/R_1 + 1/R_2 + 1/R_{\text{transistor}} &= 1/(10 \text{ k}\Omega) + 1/(5 \text{ k}\Omega) + 1/R_{\text{transistor}} \\ R_{\text{transistor}} &= \beta r_{\text{BE}} \approx 1 \text{ k}\Omega \text{ for } I_{\text{C}} = 2.5 \text{ mA}, \ \beta = 100 \text{ (see rule d)}. \\ Z_{\text{input}} &= 800 \ \Omega. \end{split}$$

8) We now need to find values for the three capacitors,  $C_{\rm E}$ ,  $C_{\rm in}$ , and  $C_{\rm out}$ .

 $C_{\rm E}$  must provide an AC ground for the emitter so we must have:

$$X_{\rm CE} = 1/(2\pi f C_{\rm E}) << R_{\rm E} = 1.75 \; {\rm k}\Omega.$$

Let  $X_{\text{CE}} = R_{\text{E}}/10$ . The lowest frequency we are concerned with is 30 Hz so:

$$C_{\rm E} = 1/(2\pi f X_{\rm CE}) = 1/(2\pi\,{\rm x}~30~{\rm x}~(R_{\rm E}/10)) = 30~\mu{\rm F}.$$

9) Finally we need to choose  $C_{\rm in}$  and  $C_{\rm out}$ . Pick these capacitors so we have the -3 dB points at 30 Hz. Remember  $\omega_{\rm 3dB} = 1/RC$ . For the input  $R \approx 800~\Omega$  and for the output  $R \approx 1~{\rm M}\Omega$  (scope

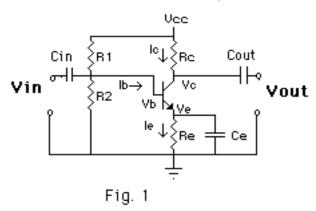
$$C_{\rm in} \approx 1/(800 \ \Omega \ 2\pi \ 30) = 6 \ \mu \text{F}$$

resistance). Thus we have:

$$C_{\rm out} \approx 1/(1~{\rm M}\Omega~2\pi~30) = 0.005~\mu{\rm F}$$

We have now determined all R's and C's. When you build the circuit don't be too disappointed (or surprised) if your measurements are different than the above calculations. We used a very simple model of the transistor.

# Common Emitter Amp



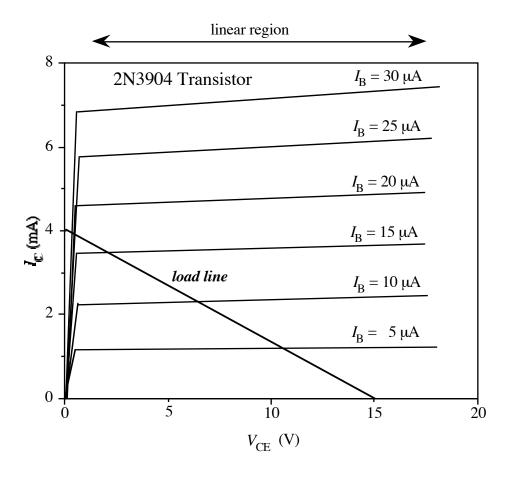


Fig. 2: 2N3904 Spec Sheet.